

FDP2614

N-Channel PowerTrench[®] MOSFET 200 V, 62 A, 27 m Ω

Features

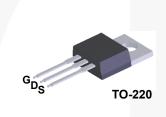
- $R_{DS(on)}$ = 22.9 m Ω (Typ.)@ V_{GS} = 10 V, I_D = 31 A
- · Fast Switching Speed
- Low Gate Charge
- High Performance Trench technology for Extremely Low $R_{\text{DS}(\text{on})}$
- High Power and Current Handing Capability
- RoHS Compliant

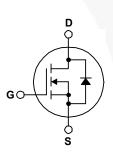
General Description

This N-Channel MOSFET is producedusing Fairchild Semiconductor's advanced PowerTrench[®] process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Consumer Appliances
- Synchronous Rectification
- Battery Protection Circuit
- Motor Drives and Uninterruptible Power Supplies





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol		Parameter		FDP2614	Unit
V _{DS}	Drain-Source Voltage		200	V	
V _{GS}	Gate-Source Voltag	е		± 30	V
ID	Drain Current	- Continuous (T _C = 25°C) - Continuous (T _C = 100°C)		62 39.3	A A
I _{DM}	Drain Current	- Pulsed	(Note 1)	see Figure 9	A
E _{AS}	Single Pulsed Avala	inche Energy	(Note 2)	145	mJ
dv/dt	Peak Diode Recove	ery dv/dt	(Note 3)	4.5	V/ns
P _D	Power Dissipation	(T _C = 25°C) - Derate above 25°C		260 2.1	W W/°C
T _{J,} T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	FDP2614	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max.	0.48	°C/W
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W

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Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP2614	FDP2614	TO-220	Tube	N/A	50 units

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter Conditions		Min	Тур	Max	Unit
Off Charac	teristics					<u> </u>
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A, T_J = 25^{\circ}C$				V
ΔBV_{DSS} / ΔT_{J}	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$, Referenced to 25°C		0.2		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 200V, V_{GS} = 0V$ $V_{DS} = 200V, V_{GS} = 0V, T_J = 125^{\circ}C$			10 500	μΑ μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V_{GS} = 30V, V_{DS} = 0V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse V _{GS} = -30V, V _{DS} = 0V				-100	nA
On Charac	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	3.0	4.0	5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10V, I _D = 31A		22.9	27	mΩ
9 _{FS}	Forward Transconductance	luctance $V_{DS} = 10V, I_D = 31A$		72		S
Dynamic C	haracteristics					
C _{iss}	Input Capacitance			5435	7230	pF
C _{oss}	Output Capacitance	− V _{DS} = 25V, V _{GS} = 0V − f = 1 0MHz		505	675	pF
C _{rss}	Reverse Transfer Capacitance			110	165	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time			77	165	ns
t _r	Turn-On Rise Time	$V_{DD} = 100V, I_D = 62A$ $V_{GS} = 10V, R_{GEN} = 25\Omega$		284	560	ns
t _{d(off)}	Turn-Off Delay Time			103	220	ns
t _f	Turn-Off Fall Time	(Note 4)		162	335	ns
Qg	Total Gate Charge			76	99	nC
Q _{gs}	Gate-Source Charge	V _{DS} = 100V, I _D = 62A V _{GS} = 10V		35		nC
Q _{gd}	Gate-Drain Charge	(Note 4)	-	18		nC
Drain-Sour	rce Diode Characteristics and Maximur	n Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				62	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				186	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0V, I _S = 62A			1.2	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0V, I _S = 62A		145		ns
Q _{rr}	Reverse Recovery Charge	dI _F /dt =100A/µs		0.81		μC

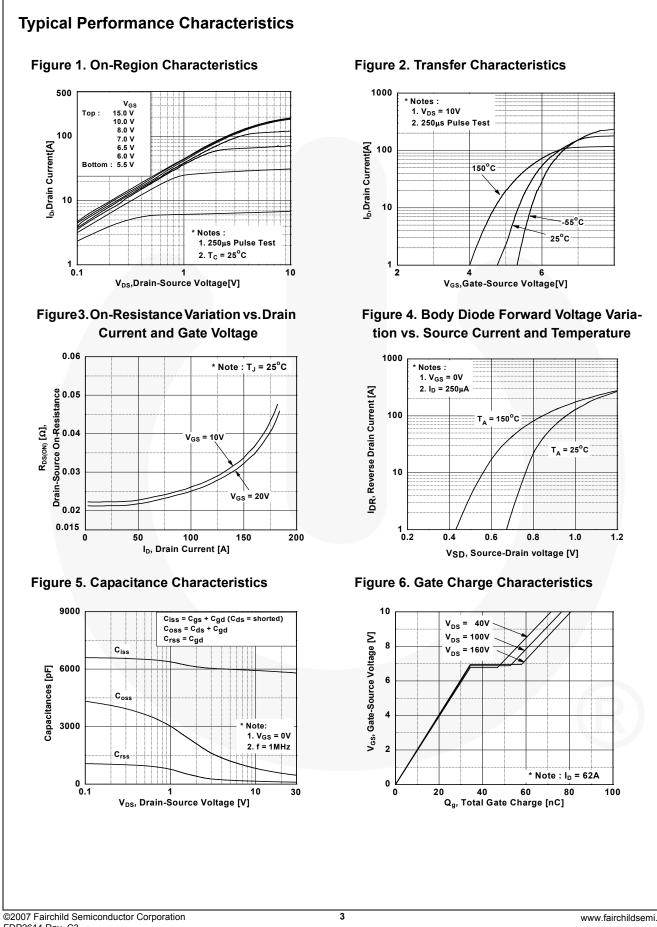
Notes:

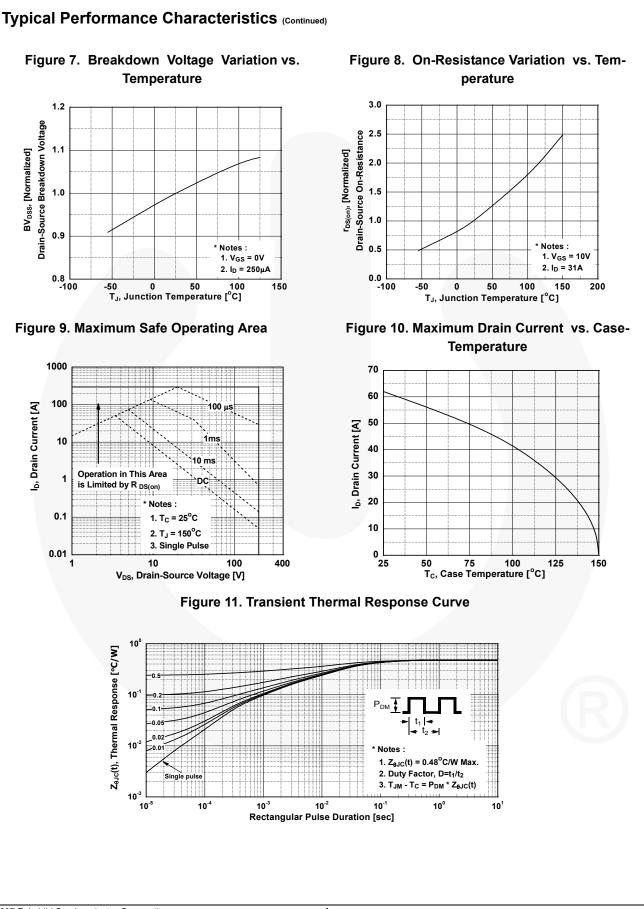
1. Repetitive Rating: Pulse width limited by maximum junction temperature

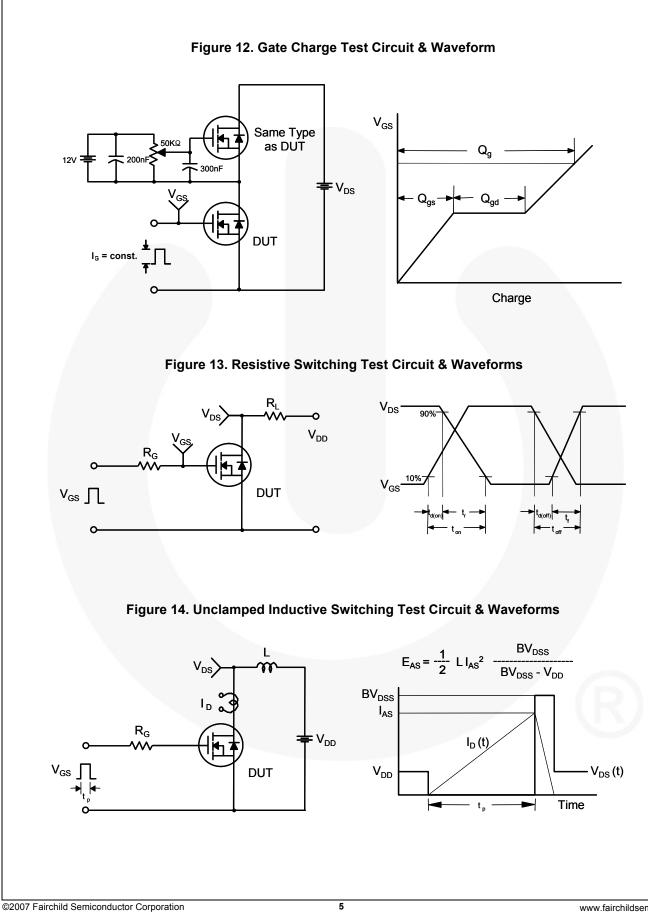
2. L = 1mH, I_{AS} = 17A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25°C

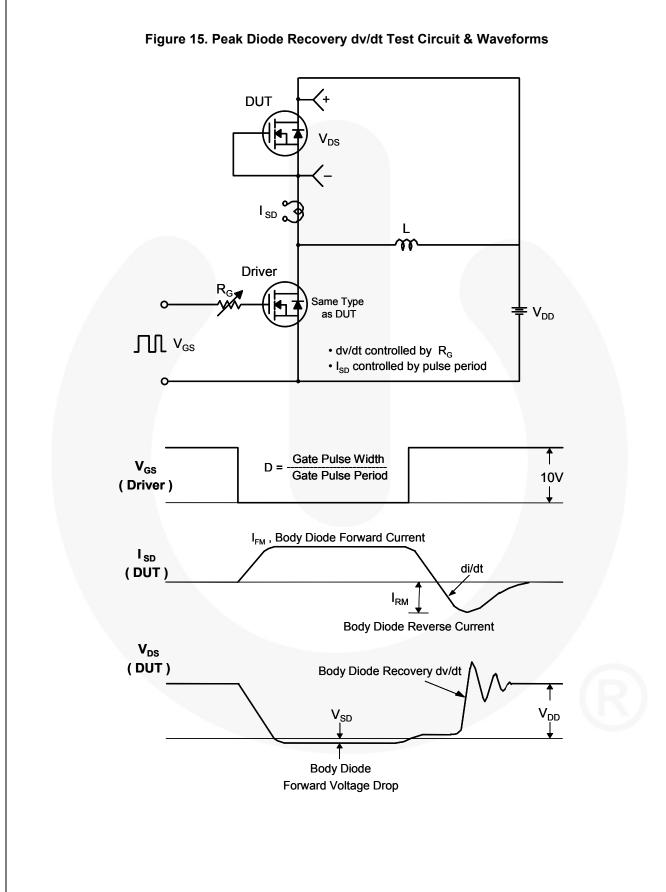
3. $I_{SD} \leq$ 62A, di/dt \leq 100A/µs, $V_{DD} \leq BV_{DSS},$ Starting T_J = 25°C

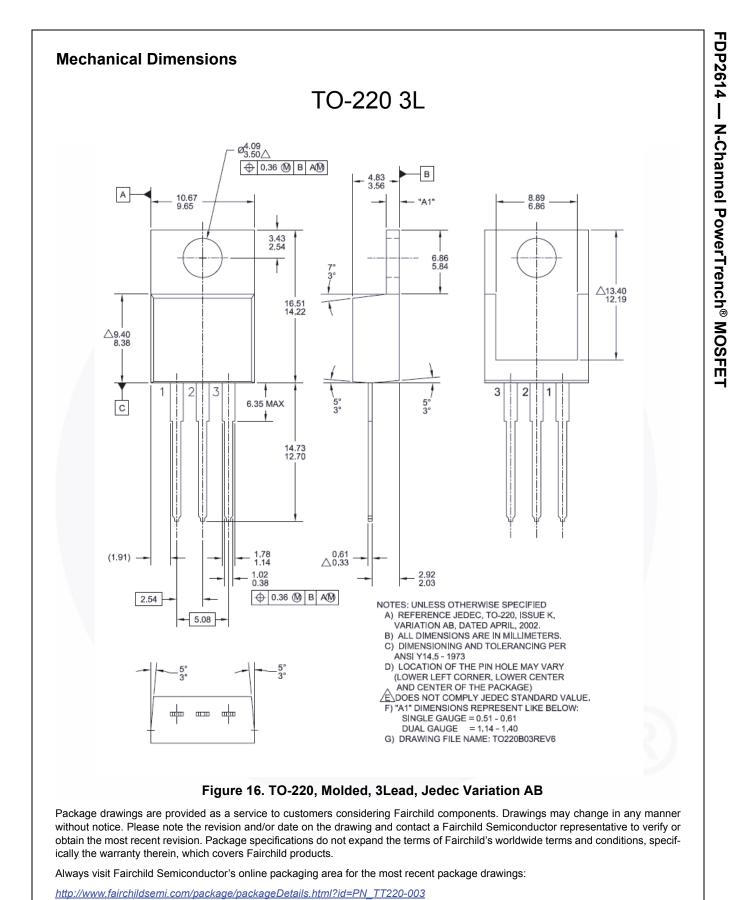
4. Essentially Independent of Operating Temperature Typical Characteristics











Dimension in Millimeters



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